



# WIDEBAND DRIVER AMPLIFIER MODULE, 2 - 35 GHz

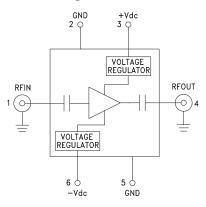


## **Typical Applications**

The HMC-C038 Wideband Driver is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

## **Functional Diagram**



#### **Features**

Gain: 12 dB @ 10 GHz

P1dB Output Power: +18 dBm @ 10 GHz Regulated Supply and Bias Sequencing

Hermetically Sealed Module

Field Replaceable 2.92 mm Connectors
-55 °C to +85 °C Operating Temperature

## **General Description**

The HMC-C038 is a GaAs PHEMT MMIC Distributed Power Amplifier in a miniature, hermetic module with replaceable 2.92mm connectors which operates between 2 and 35 GHz. The amplifier provides 12 dB of gain, +29 dBm output IP3 and up to +18 dBm of output power at 1 dB gain compression. Gain flatness is excellent from 2 - 16 GHz making the HMC-C038 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are DC blocked. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

## Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, +Vdc = +11V to +16V, -Vdc = -4V to -12V

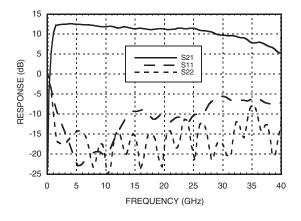
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		2 - 15			15 - 27			27 - 35		GHz
Gain	9	12		8	11		6	9		dB
Gain Flatness		±0.5			±0.4			±1.5		dB
Gain Variation Over Temperature		0.02	0.03		0.02	0.03		0.02	0.03	dB/ °C
Noise Figure		3.0			4.0			6.0		dB
Input Return Loss		15			10			6		dB
Output Return Loss		15			13			13		dB
Output Power for 1 dB Compression (P1dB)	15	18		13	16		10	14		dBm
Saturated Output Power (Psat)		20			18.5			15.5		dBm
Output Third Order Intercept (IP3)		29			26			25		dBm
Positive Supply Current (+IDC)		92			92			92		mA
Negative Supply Current (-IDC)		5.3			5.3			5.3		mA



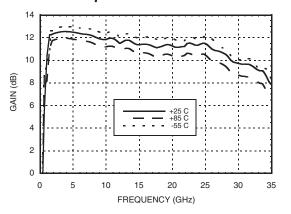


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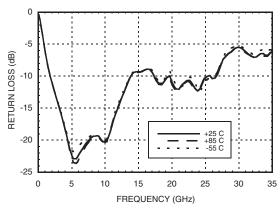
#### Gain & Return Loss



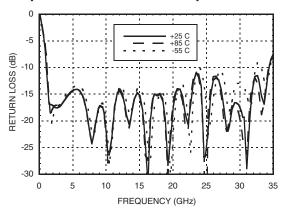
## Gain vs. Temperature



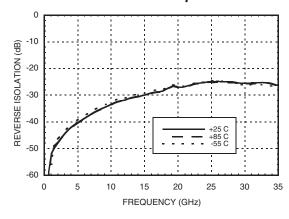
## Input Return Loss vs. Temperature



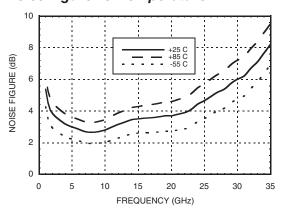
## Output Return Loss vs. Temperature



## Reverse Isolation vs. Temperature



## Noise Figure vs. Temperature

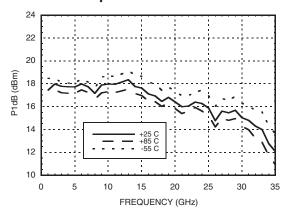




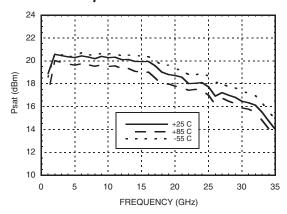


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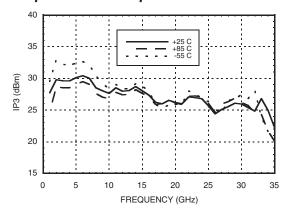
## P1dB vs. Temperature



## Psat vs. Temperature



## Output IP3 vs. Temperature



## **Absolute Maximum Ratings**

Positive Bias Supply Voltage (+Vdc)	+17V Max	
Negative Bias Supply (-Vdc)	-16V Min.	
RF Input Power (RFIN)	+23 dBm	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	







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## **Pin Descriptions**

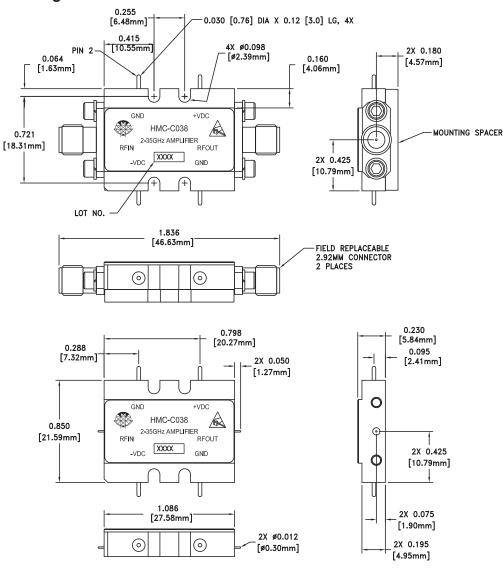
Pin Number	Function	Description	Interface Schematic		
1	RFIN & RF Ground	RF input connector, 2.92 mm female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFIN 0		
2, 5	GND	Power supply ground.	GND =		
3	+Vdc	Positive power supply voltage for the amplifier.	+Vdc O VOLTAGE REGULATOR -		
4	RFOUT & RF Ground	RF output connector, 2.92 mm female field replaceable. This pin is AC coupled and matched to 50 Ohms.			
6	-Vdc	Negative power supply voltage for the amplifier	-Vdc O VOLTAGE REGULATOR		





## WIDEBAND DRIVER AMPLIFIER MODULE, 2 - 35 GHz

## **Outline Drawing**



VIEW SHOWN WITH CONNECTORS REMOVED

## Package Information

•			
Package Type	C-10		
Package Weight [1]	18.7 gms <sup>[2]</sup>		
Spacer Weight	3.3 gms <sup>[2]</sup>		

[1] Includes the connectors

[2] ±1 gms Tolerance

#### NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. TOLERANCES:
- $4.1 .XX = \pm 0.02$
- $4.2.XXX = \pm 0.010$
- 5. FIELD REPLACEABLE 2.92mm CONNECTORS TENSOLITE 231CCSF OR EQUIVALENT



**AMPLIFIERS** 

**ANALOG DEVICES** 



Notes:

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